

L Number	Hits	Search Text	DB	Time stamp
1	0	dual adj gate adj MOSFET and shielding adj gate and switching and conduction and blocking adj mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:24
2	0	dual adj gate adj MOSFET and shielding with gate and switching and conduction and blocking adj mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:24
3	0	dual adj gate adj MOSFET and shielding with gate and switching and conduction and blocking with mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:25
4	0	(dual or double) adj gate adj MOSFET and shielding with gate and switching and conduction and blocking with mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:25
5	0	(dual or double) adj gate near10 MOSFET and shielding with gate and switching and conduction and blocking with mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:25
6	0	(dual or double) adj gate with MOSFET and shielding with gate and switching and conduction and blocking with mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:25
7	0	(dual or double) near5 gate with MOSFET and shielding with gate and switching and conduction and blocking with mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:25
8	0	(dual or double) near5 gate\$2 with MOSFET and shielding with gate and switching and conduction and blocking with mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:26
9	0	(dual or double) near5 gate\$2 with MOSFET and shielding and switching and conduction and blocking with mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:27
10	4	(dual or double) near5 gate\$2 and shielding and switching and conduction and blocking with mode	USPAT; EPO; JPO; DERWENT	2004/10/29 21:27